

Continental Device India Limited An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



2N5191 2N5192

TO126

Plastic Package

NPN EPITAXIAL SILICON POWER TRANSISTORS

E C B

Use in Medium Power Linear and Switching Applications

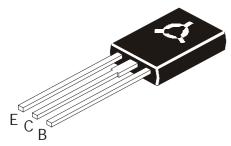
ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	2N5191	2N5192	UNIT
Collector -Base Voltage	V _{CBO}	60	80	V
Collector -Emitter Voltage	V _{CEO}	60	80	V
Emitter Base Voltage	V _{EBO}	5		V
Collector Current	I _C	4		А
Collector Peak Current	I _{CM} 7		А	
Base Current	I _B 1		А	
Total Dissipation @ T _c <25 °C	P _{tot}			W
Junction Temperature	T _i 150		°C	
Storage Temperature Range	T _{stg}	T _{stg} -65 to 150		°C
Thermal Resistance				
Junction to Case	Rth(j-c)	3.12		°C/W
Junction to Ambient	Rth(j-a)	Rth(j-a) 100		°C/W

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	SYMBOL TEST CONDITION		TYP	MAX	UNIT
Collector Emitter Sustaining Voltage	V _{CEO*(sus)}	I _C =100mA, I _B =0				
		2N5191	60	-	-	V
		2N5192	80	-	-	V
Collector Cut off Current	I _{CBO}	V _{CB} =rated V _{CBO,} I _E =0	-	-	0.1	mA
	I _{CEX}	V _{CE} =rated V _{CEO} ,	-	-	0.1	mA
		VBE=1.5V				
		V _{CE} =rated V _{CEO} , V _{BE} =1.5V,T _C =125 ⁰C	-	-	2	mA
	I _{CEO}	V_{CE} =rated V_{CEO} , $I_{B}=0$	-	-	1	mA
Emitter Cut off Current	I _{EBO}	$V_{FB}=5V, I_{C}=0$	-	-	1	mA
Collector Emitter Saturation Voltage		I _C =1.5A, I _B =0.15A	-	-	0.6	V
		$I_{c} = 4A, I_{B} = 1A$	-	-	1.4	V
Base Emitter Voltage	V _{BE} *	I _C =1.5A, V _{CE} =2V	-	-	1.2	V

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DESCRIPTION	SYMBOL	SYMBOL TEST CONDITION			MAX	UNIT
DC Current Gain	h _{FE ∗}	I _C =1.5A, V _{CE} =2V				
		2N5191	25	-	100	
		2N5192	20	-	80	
		I _C =4A, V _{CE} =2V				
		2N5191	10	-	-	
		2N5192	7	-	-	
Transition frequency	f _T	I _C =1A, V _{CE} =10V	2	-	-	MHz

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MIN

7.4

10.5

DIM

А

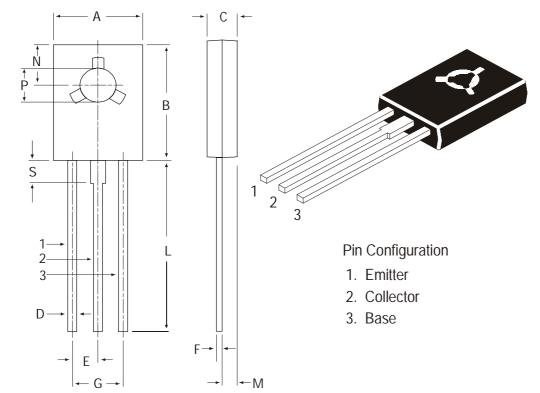
В

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MAX

7.8

10.8



TO-126 (SOT-32) Plastic Package

С	2.4	2.7			
D	0.7	0.9			
E	2.25 TYP.				
F	0.49	0.75			
G	4.5 TYP.				
L	15.7 TYP.				
М	1.27 TYP.				
Ν	3.75 TYP.				
Р	3.0	3.2			
S	2.5 TYP.				

All diminsions in mm.

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-126 Bulk	500 pcs/polybag	340 gm/500 pcs	3" x 7.5" x 7.5"	2K	17" x 15" x 13.5"	32K	31 kgs
TO-126 Tube	50 pcs/tube	73 gm/50 pcs	3" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	15 kgs

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Disclaimer

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